

DEPARTMENT OF MECHATRONIC ENGINEERING **COURSE SYLLABUS**

Course Details										
Code					Academic Year			Semester		
ETE 311					3			1		
Title						Α	L	ECTS		
Electronics I : Semiconductor Components					3	1	1	6		
Language	German									
Level	Undergraduate	x	X Graduate			Р	ostgra	duate		
Department / Program	Mechatronics Engi	neering								
Forms of Teaching and Learning	Face-to-face study									
Course Type	Compulsory		X		Elective					
Objectives	The aim of this course is to understand the basic circuit elements and semiconductor elements used in electronic circuits, to gain the ability to measure, robustness test and use, to gain the ability of diode and transistor, used in DC and AC circuits to become.									
Content	 PN connection: load transfer, diffusion voltage, Boltzmann factor, Characteristic, breakthrough, barrier layer / diffusion capacity, Small signal response, charge switching behavior of the control model, Diodes: PIN diodes, tunnel / zener diodes, photo diodes, solar cells, LEDs, Semiconductor laser diode circuits, - Bipolar transistor: circuit based on the input and output characteristics, Functional principle, input and output characteristics of the emitter circuit, Early effect, increase in capacity, static, dynamic behavior, MOS transistor: MOS varactor, inversion, metal-semiconductor contact, Characteristic, channel clamping, equivalent circuit, limit frequency, Simulation parameters, short channel, thyristor, power MOS, IGBT 									
Prerequisites	-									
Coordinator	-									
Lecturer(s)	-									
Assistant(s)	-									
Work Placement	-									
Recommended or Required Reading										
Books / Lecture Notes	 Semiconductor circuit technology, Ulrich Tietze, Christoph Schenk, Eberhard Gamm, Springer, 15. Baskı, 2016 Microelectronic Circuits, Adel Sedra, Kenneth Smith, Oxford, 7. Baskı, 2015 									
Other Sources	-									
Additional Course Material										
Documents	-									



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	COORSE 3							
Assignments	5 Homeworks							
Exams	1 Midterm exam, 1 Final exam							
Course Composition								
Mathematics und Basic Sciences			20 %					
Engineering			20 %					
Engineering Design			20 %					
Social Sciences			%					
Educational Sciences			%					
Natural Sciences			%					
Health Sciences			%					
Expert Knowledge			40 %					
Assessment								
Activity	Cou	nt	Percentage (%)					
Midterm Exam	1	30						
Quiz								
Assignments	5	20						
Attendance								
Recitations								
Projects								
Final Exam	1	50						
		100						
ECTS Points and Work Load								
Activity	Count	Duration	Work Load (Hours)					
Lectures	14	4	56					
Self-Study								
Assignments	5	3	15					
Presentation / Seminar Preparation								
Midterm Exam	1	8	8					
Recitations	14	4	56					
Laboratory	14	2	28					
Projects								
Final Exam	1	10	10					
		Total Work Load	173					
	6							
Learning Outcomes								

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			0001025					
1	Basics of mat	hematics and s	science					
2	Basics of engineering Skills for using software tools							
3	Definition of problems in the field of engineering, development and implementation of solution approaches							
4	Experimental basis and interpretation of the results							
5	Interdisciplin	Interdisciplinary learning skills						
6	Ability to wo	rk in groups						
7	Preparation f	or the lifelong	learning proce	ess				
8	Ethics, aware	eness of safety,	health, the en	vironment and	d social contrib	oution		
9	Engineering a	applications						
10	Social science	e skills						
11	Oral and written communication and presentation skills							
12								
Weekly Conter	nt							
1	Use of measuring equipment, pn semiconductor diode structure, distribution of the Electron hole densities							
2	Equivalent circuit diagrams for diodes with simulation programs							
3	Investigation of the diode properties							
4	Rectifiers with peak and mean value							
5	Trim and clamp circles							
6	Structure and operating point of the Bipolar Junction Transistor (BJT)							
7	Intermediate exams							
8	Zener diode characteristics, voltage stabilization with Zener diode							
9	Input and output characteristics of the BJT transistor							
10	Functioning of common emitter and basal connections							
11	Dynamic operation of the articulated collector connection							
12	Field effect transformers (JFET, MOSFET)							
13	Input / output characteristics, common source, common drain and Common gate circuit structures							
14	DC Analysis and Applications of FET Circuits							
15	15 Final exam							
Contribution of Learning Outcomes to Program Objectives (1-5)								
	P1	P2	P3	P4	P5	P6	P7	
1								
2								



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Contribution Level 1: Low 2: Low-intermediate 3: Intermediate 4: High 5: Very High							
Compiled by:							
Date of Compilation:							